

# TCLT101. Series

RoHS

COMPLIANT

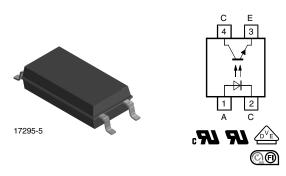
HALOGEN

FREE <u>GREEN</u>

(5-2008)

**Vishay Semiconductors** 

# Optocoupler, Phototransistor Output, LSOP-4, 110 °C Rated, Long Mini-Flat Package



#### DESCRIPTION

The TCLT101. series consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4-lead LSOP package.

#### APPLICATIONS

- Switchmode power supplies
- Computer peripheral interface
- Microprocessor system interface

#### FEATURES

- SMD low profile 4 lead package
- High isolation 5000 V<sub>RMS</sub>
- CTR flexibility available see order information
- Extra low coupling capacitance
- Connected base
- DC input with transistor output
- Temperature range -55 °C to +110 °C
- Creepage distance > 8 mm
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### AGENCY APPROVALS

- UL1577, file no. E76222
- cUL file no. E76222, equivalent to CSA bulletin 5A
- DIN EN 60747-5-5
- FIMKO: EN 60950

ORDERING INFORMATION									
T					LSOP-	SOP-4			
			PART NU	JMBER				<b>⊲</b> 10.2 m	m 🔸
AGENCY					CTR	1 (%)			
CERTIFIED/PACKA	AGE	5 mA	10	mA			5 mA		
UL, cUL, VDE, FIMI	ко	50 to 600	63 to 125	100 to 200	50 to 150	100 to 300	80 to 160	130 to 260	200 to 400
LSOP-4		TCLT1010	TCLT1012	TCLT1013	TCLT1015	TCLT1016	TCLT1017	TCLT1018	TCLT1019

<b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_{amb} = 25 \text{ °C}$ , unless otherwise specified)								
PARAMETER	RAMETER TEST CONDITION SYMBOL VALUE UNIT							
INPUT								
Reverse voltage		V <sub>R</sub>	6	V				
Forward current		l <sub>F</sub>	60	mA				
Forward surge current	t <sub>p</sub> ≤ 10 μs	I <sub>FSM</sub>	1.5	A				
Power dissipation		P <sub>diss</sub>	100	mW				
Junction temperature		Tj	125	°C				
OUTPUT								
Collector emitter voltage		V <sub>CEO</sub>	70	V				
Emitter collector voltage		V <sub>ECO</sub>	7	V				
Collector current		I <sub>C</sub>	50	mA				
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA				
Power dissipation		P <sub>diss</sub>	150	mW				
Junction temperature		Tj	125	°C				

Rev. 1.9, 19-Jan-16

1 For technical questions, contact: <u>optocoupleranswers@vishay.com</u> Document Number: 81256

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



# TCLT101. Series

#### **Vishay Semiconductors**

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
COUPLER								
Total power dissipation		P <sub>tot</sub>	250	mW				
Operating ambient temperature range		T <sub>amb</sub>	-55 to +110	°C				
Storage temperature range	T <sub>stg</sub>	-55 to +125	°C					
Soldering temperature <sup>(1)</sup>		T <sub>sld</sub>	260	°C				

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

<sup>(1)</sup> Wave soldering three cycles are allowed. Also refer to "Assembly Instruction" (<u>www.vishay.com/doc?80054</u>).

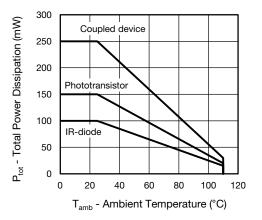


Fig. 1 - Total Power Dissipation vs. Ambient Temperature

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT		-						
Forward voltage	I <sub>F</sub> = 50 mA	V <sub>F</sub>	-	1.25	1.6	V		
Junction capacitance	$V_R = 0 V, f = 1 MHz$	Cj	-	50	-	pF		
OUTPUT				•				
Collector emitter voltage	$I_{\rm C} = 1  \rm{mA}$	V <sub>CEO</sub>	70	-	-	V		
Emitter collector voltage	I <sub>E</sub> = 100 μA	V <sub>ECO</sub>	7	-	-	V		
Collector emitter leakage current	$V_{CE} = 20 \text{ V}, \text{ I}_{F} = 0 \text{ A}$	I <sub>CEO</sub>	-	10	100	nA		
COUPLER								
Collector emitter saturation voltage	I <sub>F</sub> = 10 mA, I <sub>C</sub> = 1 mA	V <sub>CEsat</sub>	-	-	0.3	V		
Cut-off frequency	$V_{CE}$ = 5 V, I <sub>F</sub> = 10 mA, R <sub>L</sub> = 100 $\Omega$	f <sub>c</sub>	-	110	-	kHz		
Coupling capacitance	f = 1 MHz	C <sub>k</sub>	-	0.3	-	pF		

#### Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

2



### TCLT101. Series

### **Vishay Semiconductors**

CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
	$V_{CE} = 5 \text{ V}, \text{ I}_{F} = 5 \text{ mA}$	TCLT1010	CTR	50	-	600	%	
	$V_{} = 5 V_{} = 10 m \Lambda$	TCLT1012	CTR	63	-	125	%	
	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}$	TCLT1013	CTR	100	-	200	%	
	V <sub>CE</sub> = 5 V, I <sub>F</sub> = 1 mA	TCLT1012	CTR	22	45	-	%	
I <sub>C</sub> /I <sub>F</sub>		TCLT1013	CTR	34	70	-	%	
IC/IF		TCLT1015	CTR	50	-	150	%	
		TCLT1016	CTR	100	-	300	%	
	$V_{CE} = 5 \text{ V}, \text{ I}_{F} = 5 \text{ mA}$	TCLT1017	CTR	80	-	160	%	
		TCLT1018	CTR	130	-	260	%	
		TCLT1019	CTR	200	-	400	%	

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Partial discharge test voltage - routine test	100 %, t <sub>test</sub> = 1 s	V <sub>pd</sub>	1.6	kV
Partial discharge test voltage -	t <sub>Tr</sub> = 60 s, t <sub>test</sub> = 10 s,	V <sub>IOTM</sub>	8	kV
lot test (sample test)	(see figure 2)	V <sub>pd</sub>	1.3	kV
Isolation test voltage (RMS)		V <sub>ISO</sub>	5000	V <sub>RMS</sub>
	V <sub>IO</sub> = 500 V	R <sub>IO</sub>	10 <sup>12</sup>	Ω
Insulation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$	R <sub>IO</sub>	10 <sup>11</sup>	Ω
	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 150 °C (construction test only)	R <sub>IO</sub>	10 <sup>9</sup>	Ω
Forward current		I <sub>si</sub>	130	mA
Power dissipation		P <sub>so</sub>	265	mW
Rated impulse voltage		V <sub>IOTM</sub>	8	kV
Safety temperature		T <sub>si</sub>	150	°C
Clearance distance			8.0	mm
Creepage distance			8.0	mm
Insulation distance (internal)			0.40	mm

Note

 According to DIN EN 60747-5-2 (VDE 0884) (see figure 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

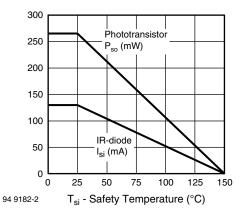


Fig. 2 - Derating Diagram

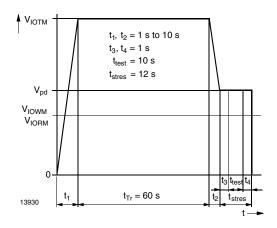


Fig. 3 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-2 (VDE 0884); IEC 60747-5-5

3

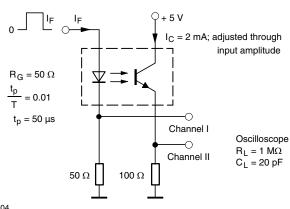
For technical questions, contact: <u>optocoupleranswers@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



# TCLT101. Series

### **Vishay Semiconductors**

SWITCHING CHARACTERISTICS ( $T_{amb} = 25 \text{ °C}$ , unless otherwise specified)									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT			
Delay time	$\label{eq:VS} \begin{array}{l} V_S = 5 \ V, \ I_C = 2 \ mA, \ R_L = 100 \ \Omega, \\ (see \ figure \ 3) \end{array}$	t <sub>d</sub>	-	3	-	μs			
Rise time	$\label{eq:VS} \begin{array}{l} V_S = 5 \ V, \ I_C = 2 \ mA, \ R_L = 100 \ \Omega, \\ (see \ figure \ 3) \end{array}$	t <sub>r</sub>	-	3	-	μs			
Fall time	$\label{eq:VS} \begin{array}{l} V_{S} = 5 \; V, \; I_{C} = 2 \; mA, \; R_{L} = 100 \; \Omega, \\ (\text{see figure 3}) \end{array}$	t <sub>f</sub>	-	4.7	-	μs			
Storage time	$\label{eq:VS} \begin{array}{l} V_S = 5 \ V, \ I_C = 2 \ mA, \ R_L = 100 \ \Omega, \\ (see \ figure \ 3) \end{array}$	ts	-	0.3	-	μs			
Turn-on time	$V_S = 5 \text{ V}, \text{ I}_C = 2 \text{ mA}, \text{ R}_L = 100 \Omega,$ (see figure 3)	t <sub>on</sub>	-	6	-	μs			
Turn-off time	$\label{eq:VS} \begin{array}{l} V_{S} = 5 \; V, \; I_{C} = 2 \; mA, \; R_{L} = 100 \; \Omega, \\ (\text{see figure 3}) \end{array}$	t <sub>off</sub>	-	5	-	μs			
Turn-on time	$\label{eq:VS} \begin{array}{l} V_S = 5 \ V, \ I_F = 10 \ mA, \ R_L = 1 \ k\Omega, \\ (see \ figure \ 4) \end{array}$	t <sub>on</sub>	-	9	-	μs			
Turn-off time	$\label{eq:VS} \begin{array}{l} V_S = 5 \ V, \ I_F = 10 \ mA, \ R_L = 1 \ k\Omega, \\ (see \ figure \ 4) \end{array}$	t <sub>off</sub>	-	10	-	μs			



95 10804

Fig. 4 - Test Circuit, Non-Saturated Operation

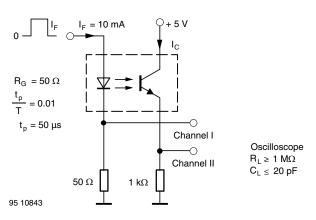


Fig. 5 - Test Circuit, Saturated Operation

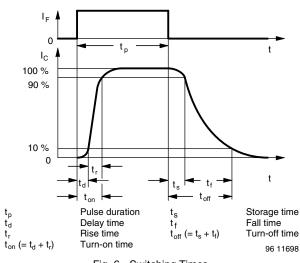


Fig. 6 - Switching Times

4



### TCLT101. Series

**Vishay Semiconductors** 

#### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

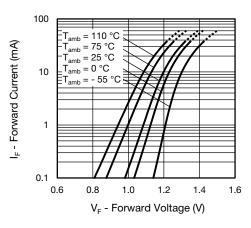


Fig. 7 - Forward Voltage vs. Forward Current

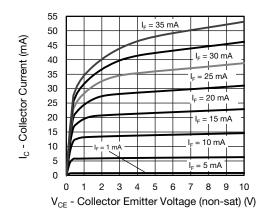


Fig. 8 - Collector Current vs. Collector Emitter Voltage (NS)

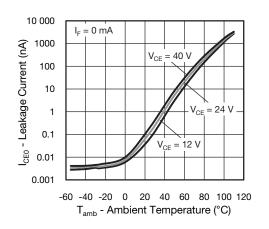


Fig. 9 - Leakage Current vs. Ambient Temperature

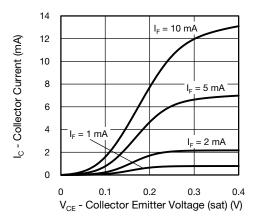


Fig. 10 - Collector Current vs. Collector Emitter Voltage (saturated)

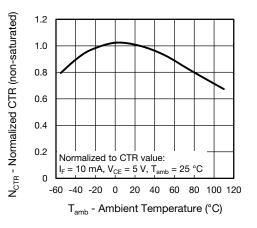


Fig. 11 - Normalized Current Transfer Ratio (non-saturated) vs. Ambient Temperature

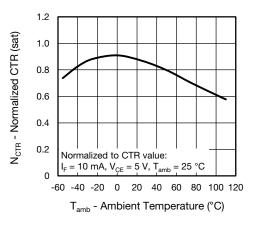


Fig. 12 - Normalized Current Transfer Ratio (saturated) vs. Ambient Temperature

5

For technical questions, contact: <u>optocoupleranswers@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



1.4 0 °C N<sub>CTR</sub> - Normalized CTR (NS) 1.2 -55 1.0 25 0.8 0.6 111 0.4 ₩ T<sub>amb</sub> = 100 °C Normalized to: 0.2  $I_{F} = 5 \text{ mA}, V_{CE} = 5 \text{ V}$ = 25 °C 0 0.1 10 100 1 I<sub>F</sub> - Forward Current (mA)

Fig. 13 - Normalized CTR (non-saturated) vs. Forward Current

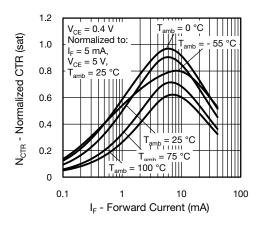


Fig. 14 - Normalized CTR (saturated) vs. Forward Current

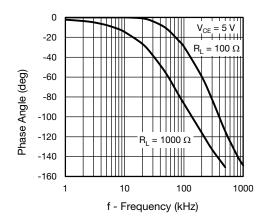


Fig. 15 - Phase Angle vs. Frequency

### **Vishay Semiconductors**

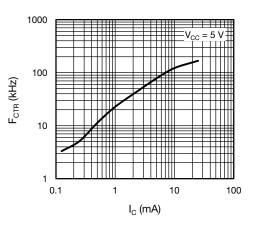


Fig. 16 - CTR Frequency vs. Collector Current

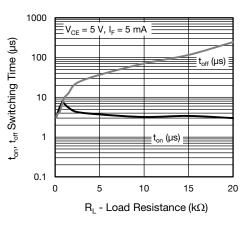


Fig. 17 - Switching Time vs. Load Resistance

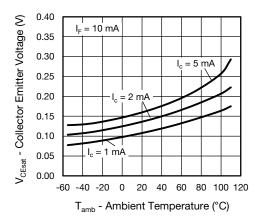


Fig. 18 - Collector Emitter Voltage vs. Ambient Temperature (saturated)

6

For technical questions, contact: <u>optocoupleranswers@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

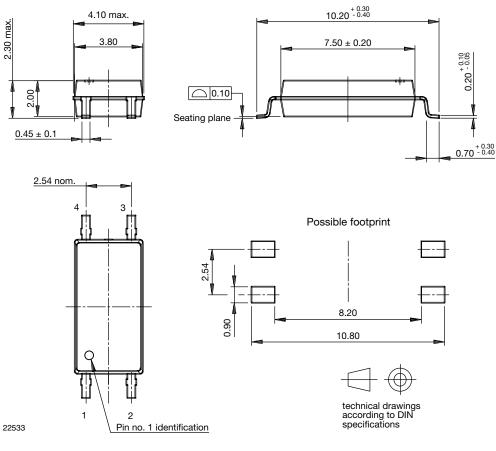
### **TCLT101. Series**

**Vishay Semiconductors** 



www.vishay.com

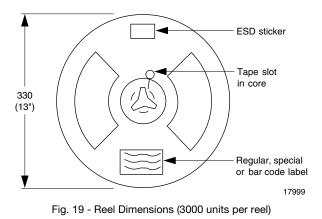
#### **PACKAGE DIMENSIONS** (in millimeters)



#### PACKAGE MARKING (example of TCLT1013)



#### TAPE AND REEL DIMENSIONS (in millimeters)



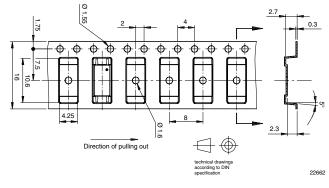


Fig. 20 - Tape Dimensions

#### Rev. 1.9, 19-Jan-16

7



TCLT101. Series

**SOLDER PROFILE** 

#### 300 max. 260 255 °C 250 245 -240 °C 217 °C Temperature (°C) 200 max. 30 s 150 max. 100 s max. 120 s 100 max. ramp down 6 °C/s 50 nax. ramp up 3 °C/s 0 0 50 100 150 200 250 300 19841 Time (s)

Fig. 21 - Lead (Pb)-free Reflow Solder Profile according to J-STD-020 **Vishay Semiconductors** 

#### HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited Conditions:  $T_{amb} < 30$  °C, RH < 85 % Moisture sensitivity level 1, according to J-STD-020



Vishay

### Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay:

TCLT1015 TCLT1016 TCLT1013 TCLT1012 TCLT1010 TCLT1017 TCLT1018 TCLT1019